

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|--------|--|---|------------------|---------|------------------|
| L1 | 310718 | (mixer or (down adj conver\$4) or (up adj conver\$4) or (frequency adj translat\$3)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L2 | 497788 | (oscillator or LO) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L3 | 23647 | (diode near5 (threshold or (turn adj on) or turnon or limit or minimum)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L4 | 22429 | ((direct adj current) or DC) near5 diode | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L5 | 4343 | (455/127.1.ccls. or 455/130.ccls. or 455/169.2.ccls. or 455/180.4.ccls. or 455/189.1.ccls. or 455/193.3.ccls. or 455/209.ccls. or 455/257.ccls. or 455/313.ccls. or 455/318.ccls. or 455/325.ccls. or 455/326.ccls. or 455/330.ccls. or 455/343.1.ccls.) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L6 | 140 | (L1 and L2 and L3 and L4) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L7 | 170 | ((three adj pair) near5 measur\$4) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L8 | 1302 | (reciproc\$5 near3 conversion) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L9 | 1572 | (327/524.ccls. or 327/530.ccls.) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |

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|-----|-----|---|---|----|----|------------------|
| L10 | 2 | "5157786".pn. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L11 | 2 | "5337014".pn. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L12 | 2 | "5678225".pn. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L13 | 2 | "5937006".pn. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L14 | 20 | L6 and L5 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L15 | 21 | (L1 and L2 and L3 and L4) and (down adj conver\$4) and (up adj conver\$4) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L16 | 39 | ((three adj pair) near5 measur\$4) and mix\$3 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L17 | 2 | L8 and (L5 or L9) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L18 | 43 | L1 and L8 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L19 | 140 | (L1 and L2 and L3 and L4) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |

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|-----|-------|---|---|----|----|------------------|
| L20 | 282 | ((reciproc\$5 or symmetric\$5 or identical) with (down adj conver\$4) with (down adj conver\$4)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L21 | 171 | ((reciproc\$5 or symmetric\$5 or identical) with (down adj conver\$4) with (down adj conver\$4)) and mix\$3 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L22 | 40826 | ((DC or (direct adj current)) near5 bias\$3) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L23 | 3873 | ((DC or (direct adj current)) near5 bias\$3) with diode | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L24 | 60 | ((DC or (direct adj current)) near5 bias\$3) with (mix\$3 near3 diode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 09:45 |
| L25 | 47 | ((DC or (direct adj current)) near5 bias\$3) with diode with (separate or dedicated) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 11:45 |
| L26 | 90 | ((DC or (direct adj current)) near5 bias\$3) with diode with (respective or unique) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 12:19 |

Interference Search

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|---|---|------------------|---------|------------------|
| L1 | 1 | (mix\$3 with (reciproc\$5 or symmetric\$5 or identical\$3) with capacit\$4 with diode with bias\$3 with volt\$3).clm. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/11 12:28 |


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Results for "((mixer <and> bias <and> diode)<in>metadata)"

Your search matched 98 of 1348795 documents.

A maximum of 100 results are displayed, 25 to a page, sorted by **Relevance in Descending** order.**» Search Options**[View Session History](#)[New Search](#)**Modify Search**

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Display Format: Citation Citation & Abstract
» Key

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View: 1-25 | 26-

IEEE JNL IEEE Journal or Magazine

1. **InGaAs-based MM-wave integrated subharmonic mixer exhibiting low inp requirement and low noise characteristics**
Marsh, P.; Hong, K.; Pavlidis, D.;
Indium Phosphide and Related Materials, 1996. IPRM '96., Eighth International
21-25 April 1996 Page(s):57 - 60
Digital Object Identifier 10.1109/ICIPRM.1996.491933
[Abstract](#) | [Full Text: PDF\(420 KB\)](#) [IEEE CNF](#)
[Rights and Permissions](#)

IEE JNL IEE Journal or Magazine

IEEE CNF IEEE Conference Proceeding

IEE CNF IEE Conference Proceeding

IEEE STD IEEE Standard

2. **Fabrication and performance of separately-biasable antiparallel-pair "T-a diodes employing a compact multiple-layer integrated bias circuit at 210**
Lee, T.-H.; Humphrey, D.A.; Dengler, R.J.; Mehdi, I.; Martin, S.C.; Pease, A.; C Smith, R.P.; Siegel, P.H.;
Microwave Symposium Digest, 1996., IEEE MTT-S International
Volume 1, 17-21 June 1996 Page(s):381 - 384 vol.1
Digital Object Identifier 10.1109/MWSYM.1996.508535
[Abstract](#) | [Full Text: PDF\(432 KB\)](#) [IEEE CNF](#)
[Rights and Permissions](#)

3. **Microwave mixers based on a novel zero bias diode**
Poppe, M.; Kleen, D.; Janson, H.; Zirath, H.; Adahl, A.;
Compound Semiconductor Integrated Circuit Symposium, 2004. IEEE
24-27 Oct. 2004 Page(s):264 - 267
[Abstract](#) | [Full Text: PDF\(605 KB\)](#) [IEEE CNF](#)
[Rights and Permissions](#)

4. **Low-parasitic, planar Schottky diodes for millimeter-wave integrated circ**
Archer, J.W.; Batchelor, R.A.; Smith, C.J.;
Microwave Theory and Techniques, IEEE Transactions on
Volume 38, Issue 1, Jan. 1990 Page(s):15 - 22
Digital Object Identifier 10.1109/22.44151
[Abstract](#) | [Full Text: PDF\(676 KB\)](#) [IEEE JNL](#)
[Rights and Permissions](#)

5. **A simple method for the evaluation of microwave mixer diodes**
Zaghloul, H.; van Kalleveen, T.H.T.; Hansen, C.H.; Buckmaster, H.A.;
Instrumentation and Measurement, IEEE Transactions on
Volume 39, Issue 6, Dec 1990 Page(s):928 - 932

Digital Object Identifier 10.1109/19.65800

[Abstract](#) | Full Text: [PDF\(320 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 6. An even harmonic mixer using self-biased anti-parallel diode pair**
Shimozawa, M.; Katsura, T.; Maeda, K.; Taniguchi, E.; Ikushima, T.; Suematsu, Isota, Y.; Takagi, T.;
[Microwave Symposium Digest, 2002 IEEE MTT-S International](#)
Volume 1, 2-7 June 2002 Page(s):253 - 256
Digital Object Identifier 10.1109/MWSYM.2002.1011605
[Abstract](#) | Full Text: [PDF\(418 KB\)](#) IEEE CNF
[Rights and Permissions](#)

- 7. A novel biased anti-parallel Schottky diode structure for subharmonic mixers**
Trong-Huang Lee; Chen-Yu Chi; East, J.R.; Rebeiz, G.M.; Haddad, G.I.;
[Microwave and Guided Wave Letters, IEEE \[see also IEEE Microwave and Wireless Components Letters\]](#)
Volume 4, Issue 10, Oct. 1994 Page(s):341 - 343
Digital Object Identifier 10.1109/75.324710
[Abstract](#) | Full Text: [PDF\(208 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 8. MOVPE-grown millimeter-wave InGaAs mixer diode technology and characterization**
Marsh, P.; Pavlidis, D.; Hong, K.;
[Electron Devices, IEEE Transactions on](#)
Volume 44, Issue 7, July 1997 Page(s):1066 - 1075
Digital Object Identifier 10.1109/16.595933
[Abstract](#) | Full Text: [PDF\(380 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 9. On the effect of IF power nulls in Schottky diode harmonic mixers**
Feinaugle, R.; Hubers, H.-W.; Roser, H.P.; Hesler, J.L.;
[Microwave Theory and Techniques, IEEE Transactions on](#)
Volume 50, Issue 1, Part 1, Jan. 2002 Page(s):134 - 142
Digital Object Identifier 10.1109/22.981257
[Abstract](#) | Full Text: [PDF\(178 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 10. A Q-band monolithic balanced diode mixer using AlGaAs/GaAs HEMT and GaAs HBT**
Chen, T.H.; Ton, T.N.; Dow, G.S.; Nakano, K.; Liu, L.C.T.; Berenz, J.;
[Microwave Symposium Digest, 1990., IEEE MTT-S International](#)
8-10 May 1990 Page(s):895 - 898 vol.2
Digital Object Identifier 10.1109/MWSYM.1990.99722
[Abstract](#) | Full Text: [PDF\(312 KB\)](#) IEEE CNF
[Rights and Permissions](#)

- 11. Design and measurements of a 210 GHz subharmonically pumped GaAs HEMT mixer**
Siegel, P.H.; Weinreb, S.; Duncan, S.; Berk, W.; Eskandarian, A.; Tu, D.-W.;
[Microwave Symposium Digest, 1992., IEEE MTT-S International](#)
1-5 June 1992 Page(s):603 - 606 vol.2
Digital Object Identifier 10.1109/MWSYM.1992.188054
[Abstract](#) | Full Text: [PDF\(316 KB\)](#) IEEE CNF
[Rights and Permissions](#)

- 12. A quasi-optical subharmonically-pumped receiver using separately biased diode pairs**
Trong-Huang Lee; Chen-Yu Chi; East, J.R.; Rebeiz, G.M.; Haddad, G.I.;
[Microwave Symposium Digest, 1994., IEEE MTT-S International](#)
23-27 May 1994 Page(s):783 - 786 vol.2

Digital Object Identifier 10.1109/MWSYM.1994.335239

[Abstract](#) | Full Text: [PDF\(484 KB\)](#) IEEE CNF

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- 13. High-sensitivity receiver for infrared laser communications**
Peyton, B.; DiNardo, A.; Kanischak, G.; Arams, F.; Lange, R.; Sard, E.;
Quantum Electronics, IEEE Journal of
Volume 8, Issue 2, Part 1, Feb 1972 Page(s):252 - 263
[Abstract](#) | Full Text: [PDF\(3792 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 14. Characteristics of metal-insulator-metal diodes as generators of far-infrared radiation**
Odashima, H.; Yamamoto, K.; Matsushima, F.; Tsunekawa, S.; Takagi, K.;
Quantum Electronics, IEEE Journal of
Volume 32, Issue 2, Feb. 1996 Page(s):350 - 356
Digital Object Identifier 10.1109/3.481883
[Abstract](#) | Full Text: [PDF\(660 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 15. A comparison of planar doped barrier diode performance versus Schottk performance in a single balanced, MIC mixer with low LO drive**
Poelker, J.N.; Robertson, R.S.;
Microwave Theory and Techniques, IEEE Transactions on
Volume 43, Issue 6, June 1995 Page(s):1241 - 1246
Digital Object Identifier 10.1109/22.390178
[Abstract](#) | Full Text: [PDF\(484 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 16. An actively balanced GaAs HBT-Schottky mixer for 3-V wireless applications**
Kobayashi, K.W.; Tran, L.T.; Oki, A.K.; Lammert, M.; Block, T.R.; Streit, D.C.;
Microwave and Guided Wave Letters, IEEE [see also IEEE Microwave and Wireless Components Letters]
Volume 7, Issue 7, July 1997 Page(s):181 - 183
Digital Object Identifier 10.1109/75.594857
[Abstract](#) | Full Text: [PDF\(64 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 17. New approach to the design and the fabrication of THz Schottky barrier diodes**
Jelenski, A.; Grub, A.; Krozer, V.; Hartnagel, H.L.;
Microwave Theory and Techniques, IEEE Transactions on
Volume 41, Issue 4, April 1993 Page(s):549 - 557
Digital Object Identifier 10.1109/22.231645
[Abstract](#) | Full Text: [PDF\(760 KB\)](#) IEEE JNL
[Rights and Permissions](#)

- 18. A 640 GHz planar-diode fundamental mixer/receiver**
Siegel, P.H.; Mehdi, I.; Dengler, R.J.; Lee, T.H.; Humphrey, D.A.; Pease, A.; Zimmerman, P.;
Microwave Symposium Digest, 1998 IEEE MTT-S International
Volume 2, 7-12 June 1998 Page(s):407 - 410 vol.2
Digital Object Identifier 10.1109/MWSYM.1998.705020
[Abstract](#) | Full Text: [PDF\(508 KB\)](#) IEEE CNF
[Rights and Permissions](#)

- 19. Design and fabrication of ultra-small GaAs Schottky barrier diodes for local oscillator applications**
Peatman, W.C.; Crowe, T.W.;
High Speed Semiconductor Devices and Circuits, 1989. Proceedings., IEEE/Circuits and Advanced Concepts in

7-9 Aug. 1989 Page(s):390 - 398
Digital Object Identifier 10.1109/CORNEL.1989.79857
[Abstract](#) | Full Text: [PDF\(628 KB\)](#) IEEE CNF
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- 20. Inherent Signal Losses in Resistive-Diode Mixers**
Hines, M.E.;
[Microwave Theory and Techniques, IEEE Transactions on](#)
Volume 29, Issue 4, Apr 1981 Page(s):281 - 292
[Abstract](#) | Full Text: [PDF\(1176 KB\)](#) IEEE JNL
[Rights and Permissions](#)
- 21. On the relationship between Schottky barrier capacitance and mixer performance at cryogenic temperatures**
Romanofsky, R. R.;
[Microwave and Guided Wave Letters, IEEE \[see also IEEE Microwave and Wireless Components Letters\]](#)
Volume 6, Issue 8, Aug. 1996 Page(s):286
Digital Object Identifier 10.1109/75.508555
[Abstract](#) | Full Text: [PDF\(192 KB\)](#) IEEE JNL
[Rights and Permissions](#)
- 22. An 18-22-GHz down-converter based on GaAs/AlGaAs HBT-Schottky diode technology**
Kobayashi, K.W.; Tran, L.T.; Oki, A.K.; Lammert, M.; Block, T.R.; Streit, D.C.;
[Microwave and Guided Wave Letters, IEEE \[see also IEEE Microwave and Wireless Components Letters\]](#)
Volume 7, Issue 4, April 1997 Page(s):106 - 108
Digital Object Identifier 10.1109/75.563634
[Abstract](#) | Full Text: [PDF\(120 KB\)](#) IEEE JNL
[Rights and Permissions](#)
- 23. A monolithic 94 GHz balanced mixer**
Adelseck, B.; Dieudonne, J.M.; Schmegner, K.E.; Colquhoun, A.; Ebert, G.; Seidel, J.;
[Microwave Symposium Digest, 1990, IEEE MTT-S International](#)
8-10 May 1990 Page(s):193 - 196 vol.1
Digital Object Identifier 10.1109/MWSYM.1990.99554
[Abstract](#) | Full Text: [PDF\(180 KB\)](#) IEEE CNF
[Rights and Permissions](#)
- 24. Temperature variable noise and electrical characteristics of Au-Ga-As Schottky-barrier diodes for millimeter-wave mixer applications**
Zirath, H.H.G.; Nilsen, S.M.; Hjelmgren, H.; Ramberg, L.P.; Kollberg, E.L.;
[Microwave Theory and Techniques, IEEE Transactions on](#)
Volume 36, Issue 11, Nov. 1988 Page(s):1469 - 1475
Digital Object Identifier 10.1109/22.8909
[Abstract](#) | Full Text: [PDF\(616 KB\)](#) IEEE JNL
[Rights and Permissions](#)
- 25. Microwave PtSi-Si Schottky-barrier-detector diode fabrication using an iron layer on high-resistivity silicon substrate**
Yunghong Wu; Armstrong, B.M.; Gamble, H.S.; Zhirun Hu; Qiang Chen; Suido V.F.; Stewart, J.A.C.;
[Microwave Theory and Techniques, IEEE Transactions on](#)
Volume 46, Issue 5, Part 2, May 1998 Page(s):641 - 646
Digital Object Identifier 10.1109/22.668676
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